

TB0640L - TB3500L

30A BIDIRECTIONAL SURFACE MOUNT THYRISTOR SURGE PROTECTIVE DEVICE

Features

- 30A Peak Pulse Current @ 10/1000μs
- 150A Peak Pulse Current @ 8/20μs
- 58 320V Stand-Off Voltages
- Oxide-Glass Passivated Junction
- Bidirectional Protection In a Single Device
- High Off-State impedance and Low On-State Voltage
- Helps Equipment Meet GR-1089-CORE, IEC 61000-4-5, FCC Part 68, ITU-T K.20/K.21, and UL497B
- UL Listed Under Recognized Component Index, File Number 156346
- Lead Free Finish/RoHS Compliant (Note 1)
- Green Molding Compound (No Halogen and Antimony) (Note 2)

Mechanical Data

- Case: SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208
- Polarity: None; Bidirectional Devices Have No Polarity Indicator
- Weight: 0.093 grams (approximate)





Top View

Bottom View

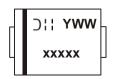
Ordering Information (Note 3)

Part Number	Case	Packaging
TB0640L-13-F	SMB	3000/Tape & Reel
TB0720L-13-F	SMB	3000/Tape & Reel
TB0900L-13-F	SMB	3000/Tape & Reel
TB1100L-13-F	SMB	3000/Tape & Reel
TB1300L-13-F	SMB	3000/Tape & Reel
TB1500L-13-F	SMB	3000/Tape & Reel
TB1800L-13-F	SMB	3000/Tape & Reel
TB2300L-13-F	SMB	3000/Tape & Reel
TB2600L-13-F	SMB	3000/Tape & Reel
TB3100L-13-F	SMB	3000/Tape & Reel
TB3500L-13-F	SMB	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
- 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic		Value	Unit
Non-Repetitive Peak Impulse Current @10/1000us	I _{pp}	30	Α
Non-Repetitive Peak On-State Current @8.3ms (one-half cycle)	I _{TSM}	15	Α
Typical Positive Temperature Coefficient for Breakdown Voltage	$\Delta VBR/\Delta T_J$	0.1	%/°C

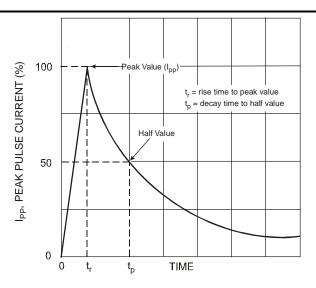
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Lead	$R_{ heta JL}$	30	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	120	°C/W
Junction Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Maximum Rated Surge Waveform

Waveform	Standard	Ipp (A)
2/10 us	GR-1089-CORE	200
8/20 us	IEC 61000-4-5	150
10/160 us	FCC Part 68	100
10/700 us (Note 4)	ITU-T, K.20/K.21	60
10/560 us	FCC Part 68	50
10/1000 us	GR-1089-CORE	30

Notes: 4. Applied 2kV, 10/700 us waveform



Electrical Characteristics @T_A = 25°C unless otherwise specified

Part Number	Maximum Rated Repetitive Off-State Voltage	Maximum Off-State Leakage Current @ V _{DRM}	Maximum Breakover Voltage	Maximum On-State Voltage @ I _T = 1A		er Current	·	Current H	Typical Off-State Capacitance	Marking Code
	V _{DRM} (V)	I _{DRM} (uA)	V _{BO} (V)	V _T (V)	Min (mA)	Max (mA)	Min (mA)	Max (mA)	C _O (pF)	
TB0640L	58	5	77	3.5	50	800	150	800	100	T064L
TB0720L	65	5	88	3.5	50	800	150	800	100	T072L
TB0900L	75	5	98	3.5	50	800	150	800	100	T090L
TB1100L	90	5	130	3.5	50	800	150	800	60	T110L
TB1300L	120	5	160	3.5	50	800	150	800	60	T130L
TB1500L	140	5	180	3.5	50	800	150	800	60	T150L
TB1800L	160	5	220	3.5	50	800	150	800	60	T180L
TB2300L	190	5	265	3.5	50	800	150	800	40	T230L
TB2600L	220	5	300	3.5	50	800	150	800	40	T260L
TB3100L	275	5	350	3.5	50	800	150	800	40	T310L
TB3500L	320	5	400	3.5	50	800	150	800	40	T350L

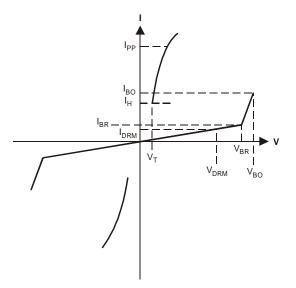


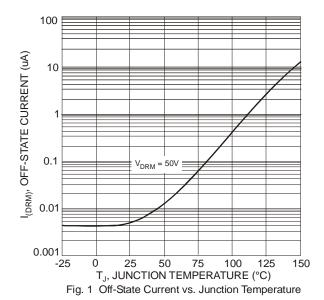
Electrical Characteristics @T_A = 25°C unless otherwise specified

Symbol	Parameter
V_{DRM}	Stand-off Voltage
I _{DRM}	Leakage current at stand-off voltage
V _{BR}	Breakdown voltage
I _{BR}	Breakdown current
V_{BO}	Breakover voltage
I _{BO}	Breakover current
lн	Holding current (Note 5)
V _T	On state voltage
Ірр	Peak pulse current
Co	Off-state capacitance (Note 6)

Notes:

- 5. I_H > (V_L/R_L) If this criterion is not obeyed, the TSPD triggers but does not return correctly to high-resistance state. The surge recovery time does not exceed 30ms. 6. Off-state capacitance measured at f = 1.0 MHz, $1.0 V_{RMS}$ signal, $V_R = 2 V_{DC}$ bias.





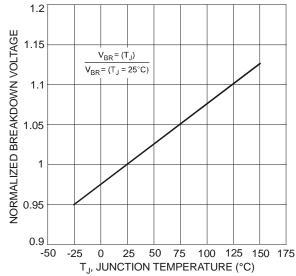


Fig. 2 Relative Variation of Breakdown Voltage vs. Junction Temperature



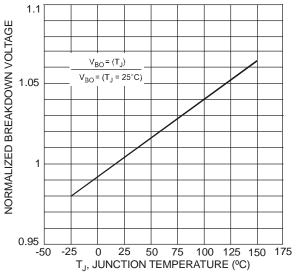


Fig. 3 Relative Variation of Breakover Voltage vs. Junction Temperature

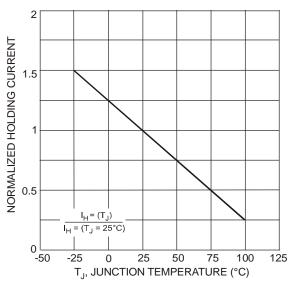


Fig. 5 Relative Variation of Holding Current vs. Junction Temperature

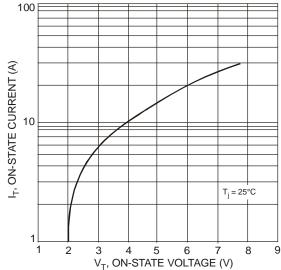


Fig. 4 On-State Current vs. On-State Voltage

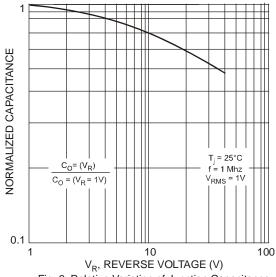
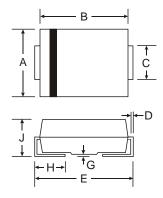


Fig. 6 Relative Variation of Junction Capacitance vs. Reverse Voltage Bias

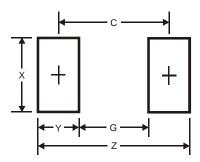
Package Outline Dimensions



SMB					
Dim	Min	Max			
Α	3.30	3.94			
В	4.06	4.57			
С	C 1.96 2.21				
D	0.15	0.31			
E 5.00 5.59					
G 0.05 0.20					
H 0.76 1.52					
J	2.00	2.50			
All Dimensions in mm					



Suggested Pad Layout



SMB Dimensions	Value (in mm)
Z	6.8
G	1.8
Х	2.3
Y	2.5
С	4.3

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